

#### 10V LOW LEAKAGE SCHOTTKY DIODE IN SOD323

## **Product Summary**

- VR > 10V
- IF = 750mA
- IR = 1μA

## **Description and Applications**

This compact SOD323 packaged Schottky diode offers users an excellent performance combination comprising high current operation, extremely low leakage and low forward voltage ensuring suitability for applications requiring efficient operation at higher temperatures (above 85°C) see Operational efficiency chart on page 4.

- Low power DC-DC conversion
- Level shifting
- Reverse blocking

## **Features and Benefits**

- Extremely low leakage
- High current capability
- Low V<sub>F</sub>, fast switching Schottky
- SOD323 package
- Package thermally rated to 150°C
- Lead, Halogen, and Antimony Free/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

## **Mechanical Data**

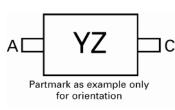
- Case: SOD323
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.0049 grams (Approximate)







Device symbol



Top View Pin Configuration

## Ordering Information (Note 3)

Device	Packaging	Shipping
ZLLS410TA	SOD323	3,000/Tape & Reel
ZLLS410TC	SOD323	10,000/Tape & Reel

Notes:

- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For Packaging Details, go to our website at http://www.diodes.com.

# **Marking Information**



41 = Product Type Marking Code



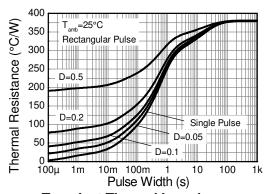
# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Continuous Reverse Voltage		$V_{R}$	10	V
Continuous Forward Current		I <sub>F</sub>	750	mA
Peak Repetitive Forward Current Rectangular Pulse Duty Cycle		I <sub>FPK</sub>	1.35	Α
Non Repetitive Forward Current	t ≤ 100µs t ≤ 10ms	I <sub>FSM</sub>	17 4	A A

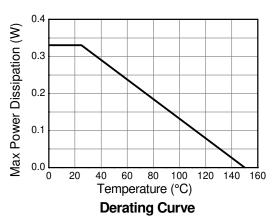
# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation, T <sub>A</sub> = 25°C			
Single Die Continuous (Note 4)	$P_{D}$	0.33	W
Single Die Measured at t < 5 secs (Note 5)		0.39	W
Junction to Ambient (Note 4)	$R_{\theta JA}$	379	°C/W
Junction to Ambient (Note 5)	$R_{\theta JA}$	317	°C/W
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

4. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. 5. For a device surface mounted on FRB PCB measured at t < 5secs. Notes:









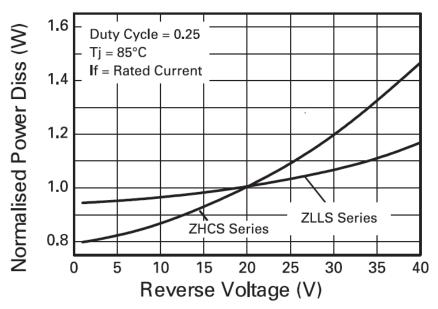
### Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	10	_	-	٧	$I_R = 200\mu A$
Forward Voltage (Note 6)	V <sub>F</sub>	- - -	285 350 500	300 380 580	mV mV mV	I <sub>F</sub> = 10mA I <sub>F</sub> = 100mA I <sub>F</sub> = 1A
Reverse Current	I <sub>R</sub>	- - -	0.5 0.7 1	4 5 6 200	μΑ μΑ μΑ μΑ	$V_{R} = 5V$ $V_{R} = 8V$ $V_{R} = 10V$ $V_{R} = 8V, T_{A} = 85^{\circ}C$
Diode Capacitance	C <sub>D</sub>	_	37	-	pF	f = 1MHz, V <sub>R</sub> = 10V
Reverse Recovery Time Reverse Recovery Charge	t <sub>rr</sub> Q <sub>rr</sub>	- -	3 210		ns pC	Switched from $I_F$ = 500mA to $V_R$ = 5.5V Measured @ $I_R$ = 50mA. di/dt = 500mA/ns, $R_{source}$ = $6\Omega$ ; $R_{load}$ = $10\Omega$

Notes:

6. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s.$  Duty cycle < 2%

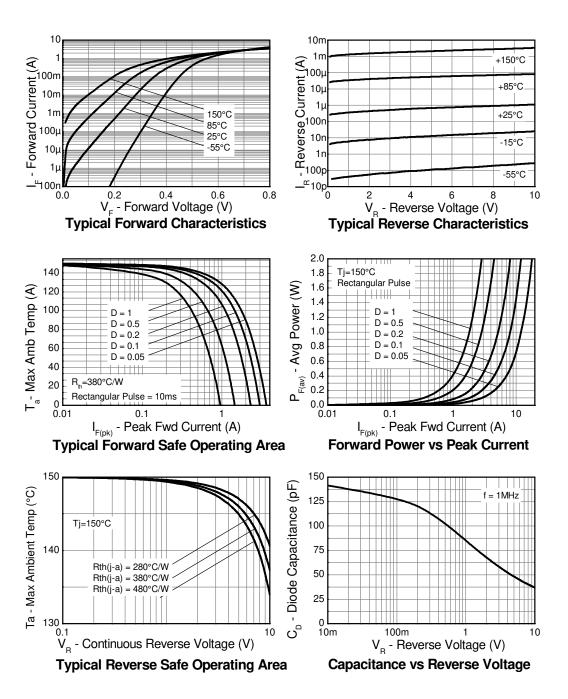
# **Operational efficiency chart**



# **Operational Efficiency Example**

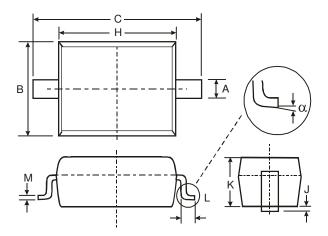
The operational efficiency chart indicates the beneficial use of the ZLLS series diodes in applications requiring higher voltage, higher temperature operation. Circuits requiring low voltage low temperature operation will benefit from using Zetex low V<sub>F</sub> ZHCS series diodes.





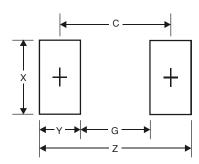


# **Package Outline Dimensions**



SOD323				
Dim	Min	Max		
Α	0.25	0.35		
В	1.20	1.40		
C	2.30	2.70		
Н	1.60	1.80		
7	0.00	0.10		
K	1.0	1.1		
L	0.20	0.40		
М	0.10	0.15		
α	0°	8°		
All Dimensions in mm				

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	3.75
G	1.05
Х	0.65
Υ	1.35
С	2.40



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